**Automotive BMS for:**

- Pure Electric vehicle
- Hybrid Electric vehicle
- High Performance Electric vehicle
- Electric motorbikes

**INTRODUCTION**

The networked LiBAL n-BMS has been developed around the new communication standard isoSPI, which essentially does not require independent programmable processors on board the slaves in the BMS network. In any application, this is a huge advantage, because it does not require software on the slave processors, and therefore greatly simplifies in-field maintenance. In addition, the isoSPI communication network facilitates the most cost efficient communication circuit in the market.

The n-BMS is developed to meet all relevant automotive requirements. ISO 26262 compliant design with key components such as Processor, ASIC and PSU are carefully selected to meet the safety standard at ASIL C rate.

The system consists of a Master Control Unit (MCU) and up to 32 Cell Monitoring Units (CMU's), that each monitor up to 12 cells in series equal to total 384 cells in series.

The n-BMS can reach temperature accuracy up to  $\pm 1^\circ\text{C}$  and cell voltage measurement accuracy of  $\pm 1.5\text{ mV}$ , throughout the entire temperature range ( $-40$  to  $+85^\circ\text{C}$ ).

The BMS Creator™ software, enable the battery designer to create a unique BMS based on the n-BMS hardware. With the BMS Creator a customized application dedicated safety strategy, battery performance as well as battery life, can be achieved.

**SAFETY**

ISO 26262 rated components and design  
Self-test and redundancy in safety critical measurement circuits  
Open circuit detection

**BATTERY LIFE**

High frequency sampling of current (down to 20 mS) allows optimal detection of pulses  
Powerful and intelligent passive balancing at 200mA per cell  
 $-40^\circ$  to  $+85^\circ\text{C}$  operational range

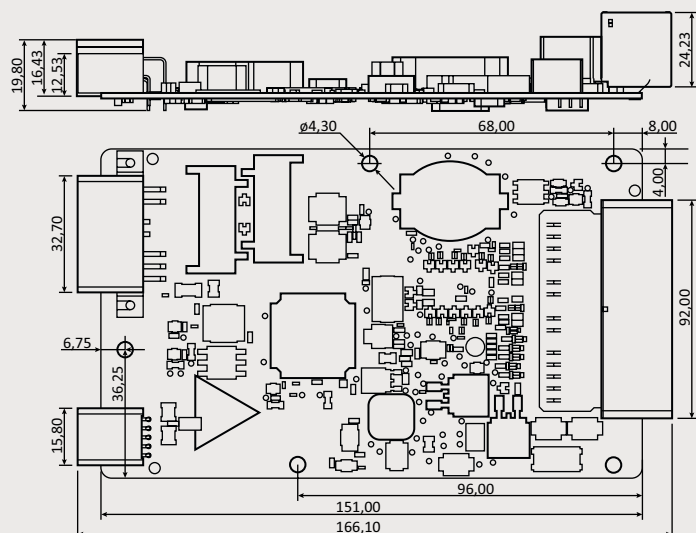
**PERFORMANCE**

$\pm 1.5\text{ mV}$  accuracy in the complete temperature range (cell voltage)  
Optimized low power consumption mode  
 $\pm 1^\circ\text{C}$  accuracy in temperature measurement

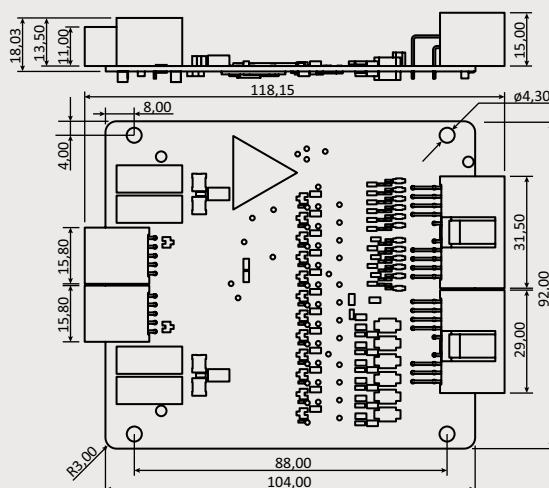
**USABILITY**

RTC + logging of events, errors and warnings  
BMS Creator PC tool for easy configuration  
Open API to build unique BMS code  
Optional current sensing (Hall effect or Shunt)  
CAN UDS tool

**Applications**



n-BMS MCU



n-BMS CMU

Dimensions in MM

## PARAMETERS

### Master Control Unit (MCU)

Power supply  
Number of CMU's supported  
Number of cells in series for total system  
Range of high voltage measurement  
Accuracy of high voltage measurement  
Range of current measurement input Shunt  
Accuracy of current measurement input Shunt  
Range of current measurement input (Hall effect sensor)  
Accuracy of current measurement input (Hall effect sensor)  
Accuracy of temperature (NTC)  
Ground fault detection (leakage) levels  
Standby Consumption  
Active Consumption  
Communication interface, master-slave  
Supported CAN communication type  
Supported CAN speeds  
Number of CAN ports  
External GPIOs  
Charger control interfaces

### Cell Monitoring Unit (CMU)

Number of cells per unit  
Detectable cell voltage  
Cell balancing topology  
Cell balancing current  
Cell voltage typical sampling time  
Accuracy of single cell voltage  
Range of Temperature measurements  
Accuracy of cell temperature (NTC)  
Communication interface  
Standby Consumption  
Active Consumption  
Patents

## SPECIFICATIONS

6-35 V  
1-32  
384  
0 - 1000 VDC  
±1 VDC  
±150 mV  
±1.0 mV -40 – 85 °C  
0.0 – 5.0 V, 0.0 -2.5 V current in, 2.5 V – 5.0 V current out  
±1.5 mV -40 – 85 °C  
±1 °C -40 – 85 °C  
250/500/1000 Ω/V Between GND and HV+/-  
<8,5 mW at 12V supply  
<3,5 W at 12 V supply  
isoSPI  
CAN 2.0A/B 11 bit and 29 bit IDs  
125, 250, 500, 1k kbit/sec  
2, one isolated CAN, one non-isolated CAN.  
16 (Active Low)  
CAN

3-12 Cells (minimum 11 V, to power the CMU)  
0 - 5 VDC  
Dissipative  
200 mA, at cell voltage 4.2 V  
100 ms (Down to 20 ms is possible)  
±1.5 mV from -40 to +85 °C  
-40 to +85 °C  
±1 °C -40 – 85 °C  
isoSPI (Max. 5 m shielded cable between boards)  
<269µW (with 12 cells @ 3,2 V)  
<326 mW (with 12 cells @ 3,2 V)  
ZT 200780048774, EP 0781788.6, US 8.350.529

